# D ispersive force betw een dissim ilar materials: geom etricale ects 

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#### Abstract

W e calculate the $C$ asim ir force or dispersive van der $W$ aals force betw een a spherical nanoparticle and a planar substrate, both $w$ ith anbitrary dielectric properties. $W$ e show that the force betw een a sphere and a plane can be calculated through the interacting surface plasm ons of the bodies. U sing a SpectralR epresentation form alism, we show that the force of a sphere $m$ ade of a $m$ aterialA and a $p l a n e m$ ade of a $m$ aterialB, di er from the case $w$ hen the sphere is $m$ ade of $B$, and the plane is $m$ ade of $A . W$ e found that the di erence depends on the plasm a frequency of the $m$ aterials, the geom etry, and the distance of separation betw een sphere and plane. T he di erences show the im portance of the geom etry, and $m$ ake evident the necessity of realistic descriptions of the sphere-plane system beyond the D erjaguin A pproxim ation or P roxim ity T heorem A pproxim ation.


## I. INTRODUCTION

The origin of dispersitive forces like C asim in in in ${ }^{1}$ and
 scopic bodies $m$ ay be attributed to electrom agnetic interactions betw een their charge distributions induced by quantum vacuum, $, \ldots c t u a t i o n s, ~ e v e n ~ w h e n ~ t h e y ~ a r e ~ e l e c-~$ trically neutrall distribution of neutral particles $m$ ay be represented by electric dipoles. This dipole approxim ation was em ployed by London to calculate the non-retarded van der W aals interaction potential $\mathrm{V}_{\mathrm{vW}}(\mathrm{z})$ betw een two identical polarizable $m$ olecules by using perturbation theory in quantum mechanic舞. Later, C asim ir studied a sim pler problem ${ }^{1 / 1}$ : the foroe betw een two parallel conducting plates separated by a distance $z$, due to the change of the zero-point energy of the classical electrom agnetic m odes. He found an interaction energy per unit area, $V_{A}(z)=\quad\left({ }^{2} \sim c=720\right)\left(1=z^{3}\right)$; where $c$ is the speed of light. In 1956, Lifshitz ${ }^{31}$ extended the theory of $C$ asim ir to dielectric sem i-in nite slabs. A decade later, it w as shown that the Lifshitz's form ula could be rederived from , the

 been perform ed to $m$ easure the $C$ asim ir force which is one of the $m$ acroscopic $m$ anifestations of the uctuations of, the, quantum vacuum ${ }_{1}^{n_{1}^{\prime}}$. M ost of these experi$m$ ents $1^{1} 111213$ have been done using a spherical surface and a plane, instead of tw o parallel planes, as originally proposed C asim in him self. The interpretation of the C asim ir force in these experim ents is based on the $P$ roxim ity Theorem, which was developed by Derjaguin and collaborators ${ }^{14}$ ! to estim ate the force betw een tw o curved surfaces of radii $R_{1}$ and $R_{2}$. The $P$ roxim ity $T$ heorem or D erjaguin A pproxim ation (DA) assum es that the force on a sm all area of one curved surface is due to locally \ at" portions on the other curved surface, such that, the force per unit area is

$$
F(z)=2 \quad \frac{R_{1} R_{2}}{R_{1}+R_{2}} \quad V(z) ;
$$

$w$ here $V(z)$ is the $C$ asim ir energy per unit area betw een parallel planes separated by a distance $z$. In the lim 止,
$w$ hen $R_{1}=R$, and $R_{2}!1$, the problem reduces to the case of a sphere of radius $R$ and a at plane, that yields to $F(z)=2 R V(z): T$ he force obtained using the DA is a power law function of $z$, where at \large" distances is proportional to $z^{3}$, while at short distances $F(z) /$ $z^{2}$. This theorem is supposed to hold when $z \quad R_{1} ; R_{2}$, how ever, the validity of the D A has not been proved yet.

In this direction, Johansonn and A pell ${ }^{151}$. studied the vW force betw een a sphere and a sem i-in nite slab. T hey calculated the electrom agnetic stress tensor associated to the electric eld correlation of the system from the G reen's function of the problem expressed in bispherical coordinates. They concluded that for sm all separations the behavior of the attractive force is consistent $w$ ith the DA. H ow ever, one draw back of this form alism is that in bispherical coordinates the section surfaces becom e planar (a point) for sm all (large) values of $z$, so that, arbitrary values of ratio of $z=R$ cannot be considered to study the sphere-plane system.
$C$ asim ir show ed that the energy $U(z)$, betw een tw o parallel perfect conductor planes can be found through the change of the-zero-point energy of the classical electromagnetic eldill like

$$
\begin{equation*}
U(z)=\frac{\sim}{2}_{i}^{X} \quad\left[!_{i}(z) \quad!_{i}(z!\quad 1)\right] ; \tag{1}
\end{equation*}
$$

where $!_{i}(z)$ are the properm odes that satisfy the boundary conditions of the electrom agnetic eld at the planes which are separated a distance $z$. For realm aterials, Lifshitz obtained a form ula to calculate the $C$ asim ir force betw een parallel dielectric planes ${ }^{3}$. The force per unit area, according to the Lifshitz form ula, is
$f(z)={\frac{\sim}{2^{2}}}^{Z^{2}} \int_{0}^{1} d Q Q{ }_{q}^{Z} d k \frac{k^{3} g}{q} R e \frac{1}{\widetilde{K}} \frac{1}{s} 1+\frac{1}{p \quad 1}$;
$w$ th $=\left[r_{1} r_{2} \exp (2 i \mathbb{K} z)\right]^{1}$, where $r_{j}$ is the re ection am plitude coe cient of the plane $j$ for the electrom agnetic eld with -polarization. Here, $j=1$, or 2 , $=s$ or $p, q=!=c$, is the frequency, $c$ is the speed of light, $q=(Q ; k)$ is the vacuum $w$ avevector $w$ th projections parallel to the surface $Q$, and norm al to the surface $k$,
$\widetilde{k}=k+i 0^{+}$, and $g$ is the photon occupation num ber of the state k .

The Lifshitz form ula depends only on the re ection coe cients of the planes and the separation betw een them. $T$ his re ection coe cients can be calculated for anbitrary m aterialusing, the surface im pedance form alism for sem iin nite slabs $11, n^{7,181}$ and for nite slabs using, for exam ple , the transfer $m$ atrix form alism 1920 . In addition, one observes that the Lifshitz formula is sym metric under the change of index $j=1!2$, it $m$ eans that the force is indistinguishable under the change of planes which is natural given the sym $m$ etry of the system.

The force betw een a sphere and a plane made of arbitrary dielectric $m$ aterials is com $m$ only calculated using the $D A$, where the $C$ asim irenergy $V(z)$ is found using the Lifshitz form ula. As a consequence, the force betw een a sphere and a plane is indistinguishable if the sphere is $m$ ade of a $m$ aterial $A$ and the plane is $m$ ade of $B$, or if the sphere is $m$ ade of $B$ and the plane is $m$ ade of $A$. Furthem ore, the DA assum es that the interaction of a sphere and a plane can be calculated as the interaction of a plane, and a set of planes, and evaluates the force by adding contributions of various distances, as if the interaction betw een planes w ere independent. H ow ever, it is well known that the C asim ir force is not an additive quantitit $4^{4} u^{2}=11$.

In this paper, we show that the geom etry of the system is im portant. W e em ploy a m ethod based on the deter$m$ ination of the proper frequencies of the system based on a spectral representation form alism 22. By calculating the zero-point energy of all the interacting surface plas$m$ ons of a sphere-plane con guration, we obtain that the force betw een dissim ilar $m$ aterials di ers if the sphere is $m$ ade of a $m$ aterial $A$ and the plane is $m$ ade of $B$, and vice versa. This provides an insight into the range of validity of the DA or P roxim ty Theorem. A lso, we nd a general form ula to calculate the C asim ir force di erences betw een arbitrary $m$ aterials $w$ hen the bodies are separated at least one radii of the sphere. In particular, we study the speci c case of alum inum and silver. We restrict ourself to the nonretarded lim it, this $m$ eans, to the case of $s m$ all particles at $s m$ all distances.

> II. ZEROTOOINTENERGYOF THE INTERACTING SURFACE PLASMONS
A. P arallel planes

In 1968, van K am pen and collaboratoraí ${ }^{\prime \prime}$ showed that the Lifshitz form ula in the nonretarded lim it is obtained from the zero-point energy of the interacting surface plasm ons of the planes. Later, $G$ erlach ${ }^{\frac{\eta}{1}}$ did an extension show ing that also in the retarded lim it the Lifshitz for$\mathrm{m} u l a$ is obtained from the zero-point energy of the interacting surface plasm ons. A com prehensive derivation of the Lifshitz form ula using the surfacem odes is also found in Ref. $\overline{1} \cdot \overline{1} \cdot 1$.

In the case of two parallel planes, in the absence of retardation, the proper electrom agneticm odes satisfy the follow ing expression ${ }^{6 / 1}$
for any value of 06 k 61 .The roots ! ${ }_{i}(\mathrm{k})$ are identi ed as the oscillation frequencies of the surface plasm ons. To nd the proper modes, it is necessary to choose a m odel for the dielectric function of the planes. To illustrate the procedure for $m$ etallic planes, let us em ploy the plasm a $m$ odel for the dielectric function, as

$$
\begin{equation*}
(!)=1 \quad \frac{!_{p}^{2}}{!^{2}} \tag{3}
\end{equation*}
$$

w th ! p the plasm a frequency. Substituting Eq. ( $\overline{\underline{3}} \overline{1}$ ) in Eq. ( $\bar{i})$, we nd tw o properm odes that, at large distances (kd 1), are given by

$$
\begin{equation*}
!\quad \frac{!p}{2} \quad 1 \quad \frac{1}{2} \exp [\quad k d] \quad \frac{1}{8} \exp [\quad 2 k d] \tag{4}
\end{equation*}
$$

and in the lim it kd! 1 , we obtain ! $=!_{p}={ }^{p} \overline{2}$ which are the frequencies of the surface plasm on of each half space. T he zero-point energy per unit area w ill be given by

$$
\begin{equation*}
E_{0}(z)=\frac{1}{2} \tilde{p} \frac{!^{2}}{2} 2 \sum_{i}^{Z_{1}} \quad{ }_{i} \quad!_{i}(k) k d k ; \tag{5}
\end{equation*}
$$

N ow, taking the di erence of the zero-point energy when the planes are at a distance $z$, and when they are at in nite, we obtain the interaction energy of the system per unit area, like

$$
\begin{equation*}
V(z)=\tilde{p} \frac{p}{2} \frac{}{16 z^{2}}: \tag{6}
\end{equation*}
$$

which depends on the energy of the surface plasm ons of the half spaces and the distance betw een planes.
B. Sphere and plane: dipolar approxim ation

N ow, let us consider the case of a sphere of radius a and dielectric fiunction $s(!)$, such that, the sphere is located at a $m$ inim um distance $z$ from the plane of dielectric function $p(!)$, as show $n$ in $F i g .1$. T he quantum vacuum uctuations $w$ ill induce a charge distribution on the sphere which also induces a charge distribution in the plane. Then, the induged 1 m th m ultipolar m om ent on the sphere is given by- ${ }^{23!}$

$$
\begin{equation*}
Q_{\operatorname{lm}}(!)=\operatorname{lm}(!) V_{\operatorname{lm}}^{\mathrm{vac}}(!)+\mathrm{V}_{\operatorname{lm}}^{\text {sub }}(!) ; \tag{7}
\end{equation*}
$$

where $\mathrm{V}_{\mathrm{lm}}^{\mathrm{vac}}(!)$ is the eld associated to the quantum vacuum uctuations at the zero-point energy, $\mathrm{V}_{\mathrm{lm}}^{\text {sub }}(!)$ is the


FIG.1: Schem atic m odel of the sphere-plane system.
induced eld due to the presence of the plane, and $\mathrm{lm}(!)$ is the lm -th polarizability of the sphere.

To illustrate the procedure in detail, rst we work in the dipolar approxim ation, i.e., when $l=1$. In section III, we will calculate the proper $m$ odes taking into account all the high-m ultipolar charge distributions. U sing the $m$ ethod of im ages, the relation betw een the dipole m om ent on the the sphere $p_{s}(!)$, and the induced dipole $m$ om ent on the plane $p_{p}(!)$, is

$$
\begin{equation*}
\mathrm{P}_{\mathrm{p}}(!)=\frac{1 \quad \mathrm{p}(!)}{1+\mathrm{p}_{\mathrm{p}}(!)} \mathrm{M} \quad \mathrm{q}(!): \tag{8}
\end{equation*}
$$

Here, $M=(1 ; 1 ; 1)$ is a diagonal $m$ atrix whose ele$m$ ents depend on the choice of the coordinate system. From Eq. ( $\overline{1} 1)$, one nds that the total induced dipole m om ent on the sphere is

$$
p_{s}(!)=(!)^{\mathrm{h}} \mathrm{E}^{\mathrm{vac}}(!)+\mathrm{T} \quad \mathrm{p}^{\mathrm{Q}}(!)^{\mathrm{i}} \text {; }
$$

where the interaction betw een dipoles is coupled by the dipole-dipole interaction tensor

$$
T=\left(\begin{array}{ll}
3 \varkappa \Vdash & r^{2} I
\end{array}\right)=r^{5}:
$$

Here, I is the identity $m$ atrix, and $x$ is the vector between the centers of the sphere and the dipole-charge distribution on the plane. From Fig. 1, we nd that $x=$ $(0 ; 0 ; 2(z+a))$, such that, $M \quad T=\left(1-\frac{3}{\underline{3}} \quad 1=r^{3} ; \quad 2=r^{3}\right)$ is a diagonalm atrix. Substituting Eq. (g) in Eq. ( $(\underline{1})$, one nds

$$
\begin{equation*}
\left.\left.\frac{1}{(!)} I+f_{C}(!) M \quad T \quad \text { d } Q!\right)=G(!) \quad \text { d! }\right)=E^{\text {vac }}(!) ; \tag{10}
\end{equation*}
$$

where G (! ) is a diagonalm atrix and

$$
f_{c}(!)=[1 \quad p(!)]=[1+p(!)]:
$$

M ultiplying Eq. ( $10-1$ ) by $a^{3}$, one nds that each term of G (!) is dim ensionless and has two parts: the lefthand side which is only associated to the $m$ aterial properties of
the sphere through its polarizability $1=\sim(!)=a^{3}=(!)$, and the right-hand side which is related to the geom etrical properties of the system trough $a$, and $z$. The righthand side also depends on the $m$ aterial properties of the plane trough the function $f_{c}(!)$.

The eigenfrequencies of the sphere-substrate system m ust satisfy Eq. (1-1 $)$, and are independent of the exciting eld, in this case $E^{\text {vac ( }!) \text {. T hese frequencies can }}$ be obtained when the determ inant of the $m$ atrix in the left-side of Eq. ( $\mathbf{1}_{1}^{-1}$ ) is equal to zero, i.e., $\operatorname{detG}(!)=0$. In this particular case, the eigen frequencies can be found from the follow ing expression

$$
\begin{equation*}
\frac{1}{\sim(!)}+\frac{f_{c}(!) a^{3}}{[2(z+a)]^{3}}{ }^{2} \frac{1}{\sim(!)}+\frac{2 f_{c}(!) a^{3}}{[2(z+a)]^{3}}=0: \tag{11}
\end{equation*}
$$

At this point, it is necessary to consider a $m$ odel for the dielectric function of the sphere to nd the properm odes. A gain, we illustrate the procedure form etallic sphere and plane, using the plasm a m odel of Eq. (了ु). M oreover, we use the fact that the polarizability of the sphere, w th in the dipolar approxim ation and in the quasi-static lim it, is given by

$$
(!)=a^{3} \frac{s(!)}{s(!)+2}:
$$

In F ig. .ina, we plot, $1=\sim(!)$ and $f_{c}(!)[2(1+z=a)]^{3}$ as a function of $!=!p$ for di erent values of $z=a$. The proper frequencies of the system are given when the black-solid line and the color-dotted lines intersect each other. We observe that there are tw o di erent properm odes foreach term on Eq. (111), giving a total of six m odes for each $z=a$. T he proper $m$ odes at the left-hand side in $F$ ig. correspond to the surface plasm on of the sphere that we denote with ! . . These $m$ odes are red-shift as the sphere approaches the plane because of the interaction betw een them. $W$ hen the separation $z=a$ increases, the $m$ odes ! + go to $!_{p}=\overline{3}$, which is the surface plasm on frequency of an isolated sphere. O $n$ the other hand, the properm odes at the right-hand side correspond to the surface plasm on of the plane and we denote them with!. These m odes are blue-shift as the sphere approaches the plane, also because of the interaction between the sphere and the plane. In this case, when the separation $z=a$ increases, the m ode! goes to ! ${ }_{p}=\frac{p}{2}$ which is the frequency of thesurface plasm on of the isolated plane. This behavior of the $m$ odes is clearly observed in $F$ ig. $\overline{2}$ and $!=!p$ are plotted as a function of $z=a$. This show $S$ that the the zero-point energy of the sphere-plane system is directly associated to the interacting surface plasm ons of the sphere and the plane.
III. EXACTCALCULATION OF THE ZEROPOINTENERGYOFA SPHEREABOVE A PLANE

In this section we calculate the proper electrom agnetic $m$ odes of the sphere-plane system, $w$ thin the non-


F IG . 2: (C olor online) (a) $P$ lot of $1=\sim$ (!) in solid line and $f_{c}(!)[2(1+z=a)]^{3}$ as a function of $!=!p$ for di erent values of $z=a$. (b) $P$ roper $m$ odes as a function of $z=a$.
retarded lim it, by including all the high-m ultipolar interactions. These proper $m$ odes are_calqulated using a Spectral Representation form alism 2 culate the zero-point energy using Eq. ( $\overline{1}_{1}^{\prime}$ ). T he Spectral $R$ epresentation (SR) form alism uses the fact that the contributions of the dielectric properties of the sphere can be separated from the contributions of its geom etricalproperties. The latter allow s to perform a system atic study of the sphere-plane system that $m$ ay be very helpful for experim entalists. The details of the $S R$ form alism can be found in Refs. 22 and 27, here we only explain it brie $y$.
$W$ e now calculate the proper $m$ odes of the system including all the high -m ultipolar charge distributions due to quantum vacuum uctuations. U sing the $m$ ethod of im ages, we nd from Eq. (7.) that the lm th m ultipolar m om ent on the sphere is

$$
\begin{aligned}
& \text { X } \\
& 1^{0} \mathrm{~m}{ }^{0} \\
& \frac{4110^{0} \mathrm{~mm}^{0}}{(21+1) 1^{0} \mathrm{~m} \circ(!)}+f_{C}(!) A_{l^{l^{0} m}}^{0} \text { (z) } Q_{1^{0} m} \circ(!)= \\
& \mathrm{V}_{\mathrm{lm}}^{\mathrm{vac}}(!) \text {; (12) }
\end{aligned}
$$

where $A_{l m}^{l^{0} m}{ }^{0}(z)$ is the $m$ atrix that, couples the interaction betw een sphere and substrate ${ }^{23}$. T he expression for
the interaction $m$ atrix $A{ }_{l m}^{1^{0} m}{ }^{0}(z)$ is given in the A ppendix section, and it show s that $A_{l m}^{1^{0} m}(z)$ depends only on the geom etrical properties of the system. If we have a hom ogeneous sphere, its polarizab,ilities are independent of the index $m$, and are given by ${ }^{23}$ -

$$
\begin{equation*}
{ }_{1}(!)=\frac{1\left[{ }_{s}(!) \quad 1\right]}{1[s(!)+1]+1} a^{2 l+1}=\frac{n_{10}}{n_{10} u(!)} a^{2 l+1} \tag{13}
\end{equation*}
$$

where $\mathrm{n}_{10}=\mathrm{l}=(21+1)$, and $\mathrm{u}(!)=[1 \quad \mathrm{~s}(!)]^{1}$. Notige that in the above equation for the polarizability, the dielectric properties of the sphere are separated from its geom etrical properties. By substituting the right-hand side of the above equation, we rew rite Eq. (12) as:

$$
\begin{align*}
& \frac{\left(\mathrm{la}^{2 l+1}\right)^{1=2}}{4} V_{l m}^{\mathrm{vac}}(!) ; \tag{14}
\end{align*}
$$

where the $\operatorname{lm} ; \mathrm{Il}^{0}$-th elem ent of the $m$ atrix $H(!; z)$ is

$$
\begin{aligned}
H_{l m}^{l^{0} m}(!; z)= & n_{1^{0} 0} 110^{0} \mathrm{~mm}^{0}+ \\
& f_{C}(!) \frac{\left(a^{1+1^{0}+1}\right)}{4}\left(110^{0}\right)^{1=2} \mathrm{~A}{\frac{l^{0} m}{}}^{0} \quad(z):(15)
\end{aligned}
$$

T he properm odes are given $w$ hen the determ inant of the quantity betw een parenthesis in Eq. ( $\left.\mathbf{1}_{1}^{1} \mathbf{I}_{1}^{\prime}\right)$ is equal to zero, $\operatorname{det}[u(!) I+H(!; z)]=0$, that is

$$
\begin{equation*}
G(!; z)={ }_{s}^{Y}\left[u(!)+n_{s}(!; z)\right]=0 \tag{16}
\end{equation*}
$$

where $n_{s}(!; z)$ are the eigenvalues of $H(!; z)$.
T he SpectralR epresentation form alism can be applied in a very sim ple w ay. $F$ irst, we have to choose a substrate to calculate the contrast factor $f_{c}(!)$, w ith this, we construct the $m$ atrix $H(!; z)$, and we diagonalize it to nd its eigenvalues $n_{s}(!; z)$. W e can repeat these steps for a set of di erent values of $z$. N otice that the eigenvahes of $H(!; z)$ can be found w thout to do any assum ption on the dielectric function of the sphere. O noe we have the eigenvalues as a function of $z$, we have to consider an explicit form of the dielectric function of the sphere, such that, we calculate the proper electrom agneticm odes $!_{\mathrm{s}}(\mathrm{z})$ trough the relation $\mathrm{u}\left(!_{\mathrm{s}}\right)=\mathrm{n}_{\mathrm{s}}(!; \mathrm{z})$.

To illustrate the procedure, we use again the plasm a model for the dielectric function of the sphere, and a plane w ith a constant dielectric function. In this case, the proper $m$ odes are given by

$$
\begin{equation*}
!_{\mathrm{s}}(z)=!_{\mathrm{p}}^{\mathrm{p}} \overline{\mathrm{n}_{\mathrm{s}}(z)} \tag{17}
\end{equation*}
$$

w ith $\mathrm{S}=(1 ; \mathrm{m})$, and $w$ here the eigenvalues $\mathrm{n}_{\mathrm{s}}(\mathrm{z})$, are independent of the frequency. $T$ he zero-point energy, according w ith Eq. (II), is given by

$$
\begin{equation*}
E(z)=\frac{\sim!}{2}_{l ; m}^{X} h_{p}{\overline{n_{l m}}(z)}_{p}^{n_{10}} \tag{18}
\end{equation*}
$$

where $\sim!_{p}^{p} \overline{n_{10}}=\sim!{ }_{p}^{p} \overline{l=(21+1)}$, are the energies associated to the $m$ ultipolar surface plasm ons resonances of the isolated sphere. H ere, $l=1 ; 2 ;::: ; L$, where $L$ is the largest order $\frac{1}{\mathrm{D}}$ the m ultipgjar expansion. For $l=1$ we have that $\sim!{ }_{p}{ }^{\rho} \overline{n_{10}}=\sim!{ }_{p}=\overline{3}$, that is the surface plas$m$ on of the sphere in the dipolar apprpxim ation. $W$ hen $1!1$, we have that $\sim!p_{p} \frac{n_{10}}{n_{10}} \sim!p=\overline{2}$.

N ow , in the presence of the dielectric plane, the proper m odes of the isolated $m$ etallic-sphere are $m$ odi ed according to Eq. (15ㄴ́). These proper $m$ odes are red-shift alw ays as the sphere approaches the plane, and this shift depends on the separation $z=a$. We nd that the interaction energy is proportional to $[1=2(1+z=a)]$, where
$=1+1^{0}+1$ is an integer between 3 and $2 L+1$. As $\mathrm{z}=\mathrm{a}!\quad 0, \mathrm{~m}$ ore and m ore m ultipolar interactions m ust be taken into account and ! 2L + 1. Finally, when the sphere is touching the plane, one would expect that $\mathrm{L}!1$, so that also ! 1 , and the energy at $z=0$ is proportionalto ( $1=2$ ), w ith ! 1 , it $m$ eans the energy becom es also in nite.

It is possible to nd the behavior of the energy as a function of $z=$ for any plasm a's sphere independently of its plasm a frequency, like $E \quad E=\sim!p$. Furthem ore, the force can be also studied independently of the radius of the sphere, since $E(z=a)$, one nds that

$$
\begin{equation*}
F=\frac{@ E(z=a)}{@ z}=\frac{@ E(z=a)}{@(z=a)} \frac{@(z=a)}{@ z} ; \tag{19}
\end{equation*}
$$

and then, we can de ne also a dim ensionless force like $a F^{r} \quad a F=\sim!p$. In sum $m$ ary, we have show $n$ that given the dielectric properties of the substrate the behavior of the energy and force is quite general, show ing the potentially of the Spectral $R$ epresentation form alism ${ }^{22} 2^{2}$.

In $F$ ig. 'inl, we show the dim ensionless energy, $E$, and force $a F^{*}$, for a sphere and a plane both described by the plasm a m odel w ith the sam e plasm a frequency. We show $E$ and $a F^{r}$ as a function of $z=a$ when all $m$ ultipolar interactions are taken into account, as well as only dipolar, and up to quadrupolar interactions are considered. $T$ he largest $m$ ultipolar $m$ om ent to achieve convergence of the energy at a minim separation of $z=a=0: 1$ is $L=80$. W e observe that $\mathrm{E}^{r}$ and $\mathrm{aF}^{r}$ are power law functions of $(z=a)$, where depends on the order of the multipolar interaction considered. Only with in the dipolar approxim ation, $E$ and $F^{\prime}$ a behaves like $(z=a)^{3}$, and $(z=a)^{4}$ for any $z$, respectively. Let us rst analyze the system when only up to quadrupolar interactions are taken into account. In that case, the energy as well as the force, show three di erent regions: (i) at large distances, $z>5 a$, only dipolar interactions are im portant, (ii) when $5 a>z>2 a$, we found that dipolarquadrupolar interactions becom e im portant and $E$ and Fra behaves like ( $\mathrm{z}=\mathrm{a})^{4}$, and ( $\left.\mathrm{z}=\mathrm{a}\right)^{5}$; while (iii) at sm all distances $z<2 a$ the quadrupolar-quadrupolar interaction dom inates, and $E$ and $F^{r}$ a behaves like $(z=a)^{5}$, and $(z=a)^{6}$, respectively
H ow ever, as the sphere approaches the substrate the interaction betw een high $m$ ultipolar $m$ om ents becom es




F IG . 3: (C olor online) (a) Energy $E$, and (b) force $a F^{r}$ as a function of $z=a$, $w$ ith $L=80$ (dotted line), $L=2$ (solid line), and $L=1$ (dashed line). (c) Force di erence, $j\left(F^{\sim L H}\right.$ $\left.F^{\sim L W}\right)=F^{\sim L H} j$ usingmultipolarm om ents $L H=80$ and $L W=$ 2 (solid line), LH $=80$ and LW $=1$ (dashed line), nally $\mathrm{LH}=2$ and $\mathrm{LW}=1$ (dot-dot-dashed line).
$m$ ore and $m$ ore im portant. T he attractive force suddenly increasesm ore than four orders ofm agnitude, as com pare $w$ ith the dipolar and quadnupolar approxim ations. In F ig. ${ }^{1} \overline{\mathrm{~T}} \mathrm{C}$ c we show the di erence of the dim ension less force, $j\left(F^{\sim L H} \quad F^{\sim L W}\right)=F^{\sim L H} j$ as a function of the separation, w ith LH and LW the highest and low est-m ultipolarm o$m$ ents taken into account. $W$ e observe that at distances $z>2 a$ the force can be obtained if up to quadrupolar interactions are considered. W e also found that for $z>7 a$ the interaction betw een the sphere and the substrate can be $m$ odeled using the dipolar approxim ation only, like in the C asim ir and P older m odeil ${ }^{28}$. H ow ever, at separations sm aller than $z<2 a$, the quadrupolar approxim ation also fails, and it is necessary to include high$m$ ultipolar contributions. For exam ple, at $z=a$ the quadrupolar approxím ation gives an error of about 10\%,
while the dipolar approxim ation gives an error of about $40 \%$. At sm aller distances like $z=a=2$, the quadrupolar approxim ation gives an error of about $40 \%$, while in the dipolar approxim ation the error is $70 \%$. At $z=0: 1 a$ both approxim ations give an error larger than $90 \%$. To directly com pare the dipolar and quadrupolar approxi$m$ ations, we also plot in Fig. . $\mathrm{LH}=2$ and LW $=1$. In this curve, we clearly observe that even at $z=5 a$ there are di erences betw een the dipolar and quadrupolar approxim ations of about 5\% .
$T$ he large increm ent of the force at sm all separations due to high-m ultipolar e ects could explain the physical origin of, for exam ple, the large deviations observed in the de ection of atom ic beam $s$ by $m$ etallic surface ${ }^{2}{ }^{29}=$ as well as som e instabilities detected in $m$ icro and nano devices. Furtherm- $Q$, to com pare experim ental data of som e experim ents $2-301$ $m$ ake a signi cant $m$ odi cation to the $C$ asim ir force. In Ref. 12 culated using D A , while in R ef.' 3 IO', the authors m easured a smaller one. Both groups argue that the discrepancies betw een theory and experim ent are due to the sam e e ect: the roughness of the surface. H ow ever, the discussion around this point has not sense until the DA be proven. Indeed, this am biguity on the interpretation of the $m$ easurem ents indicates that the force betw een a spherical particle and a planar substrate involves mose com plicated, interactions than the sim ple dipole m ode론․ or the DA1 ${ }^{144}$. For example, such deviations $m$ ight be attributed also to high-m ultipolar e ects, how ever, new experim ents have to be perform to prove the later.

In this paper, we propose a way to elucidate experi$m$ entally two im portant issues to the C asim ir force: (i) the relevance of the geom etry via the surface plasm on interactions betw een bodies, and (ii) the relevance of the high-m ultipolar interactions in the sphere-plane m odel. In the next section, we study the case of the casim ir force betw een a sphere and a plane ofdissim ilarm aterials that can help us to clarify these im portant issues.

## IV. CASIM IR FORCE BETW EEN D ISSIM ILAR MATERIALS

U sing the form alism presented in the previous section, we calculate the C asim ir force for a sphere and a plane m ade of dissim ilar $m$ aterials. To ilhustrate our results, we choose silver and alum inum whose dielectric function is described by the $D$ rude $m$ odel

$$
\begin{equation*}
(!)=1 \quad \frac{!_{p}^{2}}{!(!+i=)} ; \tag{20}
\end{equation*}
$$

w ith plasm a frequencies $\sim!\mathrm{p}=9: 6 \mathrm{eV}$, and $15: 8 \mathrm{eV}$, and relaxation tim es $(!)^{1}=0: 0019$, and $0: 04$, respectively. In this case, we em ploy the A rgum ent P rinciple (AP ) to calculate the farce. T he AP was rst used by van $K$ am pen $n^{6_{1}}$ and $G$ erlach $h^{1 \frac{1}{1}}$ to calculate the force betw een
planes. The reader can consult $R$ ef. 'A1' for a com prehensive explanation of the use of the AP ${ }^{-}$within the context of C asim ir forces.

Then, em ploying the A rgum ent $P$ rinciple $m$ ethod we nd that the sum over proper $m$ odes is given as

$$
\begin{equation*}
E(z)=\int_{s}^{X} \frac{\sim!{ }_{s}(z)}{2}=\frac{\sim}{4 i}^{I}!\frac{@ G(!; z)}{@!} \frac{1}{G(!; z)} d!; \tag{21}
\end{equation*}
$$

where $G(!; z)$ is de ned in Eq. $\left(\overline{1} \bar{\sigma}_{1}\right)$, such that

$$
\begin{equation*}
E(z)=\frac{\sim}{4 i}_{s}^{X^{I}} \quad!\frac{@}{@!} \log \left[u(!)+n_{s}(!; z)\right] d!: \tag{22}
\end{equation*}
$$

The closed contour C is de ned as the part along the im aginary axis plus the part along the sem icircle on the positive real axis. In the lim it for a in nite sem icircle radius, the integral along the sem icircle does not depend on the separation $z$, therefore, 迆 does not contribute to the force. Then, it follow s that the interaction energy of Eq. ([11) is given by
where in the last step we have perform ed a partial integration. T he force is found as in Eq. (19), where we rst perform the derivate $w$ th respect to $z$ of Eq. ( $23-3$ ) and then the integralw ith respect to !.

In $F$ ig. $\bar{A} 1$, , we show the calculated foroe for an alum inum sphere of arbitrary radius above a silver plane, $\mathrm{aF}_{\mathrm{A} l=\mathrm{A}} \mathrm{g}$, in solid line, and the same for a gold sphere above an alum inum plane, $\mathrm{aF}_{\mathrm{Ag}=\mathrm{A} 1}$, in dashed line. We nd that the di erence is sm all and cannot be directly observed. Then, in $F$ ig. ' 4 in we show the di erence of the force nor$m$ alized $w$ th the average as a function of $z=a$, given by

$$
\begin{equation*}
\mathrm{F}=2 \frac{\mathrm{~F}_{\mathrm{A}=\mathrm{B}} \quad \mathrm{~F}_{\mathrm{B}=\mathrm{A}}}{\mathrm{~F}_{\mathrm{A}=\mathrm{B}}+\mathrm{F}_{\mathrm{B}=\mathrm{A}}} ; \tag{24}
\end{equation*}
$$

with $A=A l$, and $B=A g$. Here, we observe that the difference of force varies as a function of $z=a$, such that at sm alldistances, ( $z<0: 5 a$ ) the di erence under the interchanged of $m$ aterials betw een the sphere and the plane, is less than $3 \%$. Then, the di erence increases $w$ ith the $m$ inim um separation, and at $z>a$, it has alm ost reached theirm axim um. For these particularm aterials, the maxim um is about 4:86\%, independently of the radius of the sphere. $W$ e nd that this value of $F$ is a consequence of the geom etry of the system, as we explain below .

In the previous section, we show that for a m inim um separation larger than $2 a$, the foroe can be described w ith quadrupolar interactions betw een the sphere and plane. $T h i s m$ eans that for $z>2 a$ the force varies $w$ th the sam e power-law function. This conclusion can be easily deduce from Fig. İC. We also show in section II, that the C asim ir force is given by the interaction of the surface plasm ons of the sphere and plane. In $F$ ig. observe that the proper $m$ odes of the system for $z>a$


FIG.4: (C olor online) (a) Force as a function of $z=a$, for a sphere m ade of A l over an Ag plane (solid line), and for a sphere m ade of A g over an Alplane (dashed line). (b) $D i$ erence of the force betw een a sphere $m$ ade of $A l$ over an A $g$ plane, and the force for a sphere $m$ ade of A $g$ over an A l plane.
are approxim ately given by $\sim!_{p}={ }^{p} \overline{2}$ and $\sim!{ }_{p}=\bar{p} \overline{3}$, when $\mathrm{L}=1$. T hese yield to conclude that for $\mathrm{z}>\mathrm{a}$, the foroe di erence is independent of $z$, such that

$$
\begin{align*}
& =0: 202 \frac{\sim!_{p}^{A} \quad \sim!_{p}^{B}}{\sim!_{p}^{A}+\sim!_{p}^{B}}: \tag{25}
\end{align*}
$$

For the case of $A=A 1$, and $B=A$, we nd from Eq. ( $2 \underline{5}_{1}^{-1}$ ) that $F$ ' 4:9\%, which is the calculated value shown in $F$ ig. . $\overline{4}$, b b when $\mathrm{z}>2 \mathrm{a}$. W hen $\mathrm{z}<\mathrm{a}$ the di erence decreases as $z=a$ also does, because $m$ ore and $m$ ore $m$ ultipolar interactions becom e im portant as the sphere ap-
proaches the plane. In the case of A l and Ag, the force di erence at $z=a=0: 001$ is less than $0: 01 \%$, while at $\mathrm{z}=\mathrm{a}=0: 1$ the di erence is about $1: 2 \%$. In Eq. ( $2 \overline{5} \overline{5}_{1}$ ) we observe that as the plasm a frequency of the $m$ aterials becom es $m$ ore dissim ilar the di erence of the force becom es larger. For exam ple, for potassium ( $\left.\sim!_{p}=3: 8 \mathrm{eV}\right)$ and alum inum we would nd that $F$, 12:4\% when $z>2 a$, while for gold $(\sim!p=8: 55 \mathrm{eV})$ and copper $\left(\sim!_{p}=10: 8 \mathrm{eV}\right), \mathrm{F}, 2: 4 \%$ when $z>2 \mathrm{a}$. In the other hand, the di erences becom e very sm all when $z<0: 1$ independently of the $m$ aterials because of the high -m ultipolar surface plasm ons interactions.
V. SUM M ARY

In this work, we show that the C asim ir force betw een a sphere and a plane can be calculated through the energy obtained from their interacting surface plasm ons. O ur result is in agreem ent w ith the work of van Kam pen and collaboratons ${ }^{19}$, and $G$ erlach ${ }^{17}$ that showed that the $C$ asim ir force betw een parallelplanes can be obtained from the zero-point energy ofthe interacting surface plas$m$ ons of the planes. $W$ e show that the $C$ asim ir force of a sphere $m$ ade of a given $m$ aterial $A$ and a plane $m$ ade of a given $m$ aterial $B$, is di erent from the case when the sphere is $m$ ade of $B$, and the plane is $m$ ade of $A . W$ e obtain a form ula to estim ate the force di erence for $D$ rudelike $m$ aterials, when they are separated at least tw o radii of the sphere. We nd that the di erence depends on (i) the plasm a frequency of the m aterials, and (ii) the distance of separation betw een sphere and plane. We also found that as the sphere approaches the plane, the foroe di erence becom es sm aller. W e conclude that the geom etry of the system is im portant at distances larger than the radii of the sphere, where the force is dom inated by the surface plasm ons of the bodies. T he energy of these surface plasm ons is equal to the plasm a frequency of the $m$ aterials tim es a factor given by the geom etry.

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$\star$

## A P P END IX

The tensor that couples the interaction betw een the sphere and the plane is ${ }^{5} 3^{2}=$
where $Y_{l m-}\left(;^{\prime}\right)$ are the sphericalharm onics. In sphericalcoordinates $x=(2(z+a) ; 0 ; 0)$, then , the sphericalharm onics reduce taㄹ.

$$
\begin{equation*}
Y_{l+1^{0}}^{m} m^{0}\left(0 ;^{\prime}\right)=\frac{2\left(l+l^{0}\right)+1^{\#_{1=2}}}{4} \mathrm{~m} \mathrm{~m}^{0} ; 0 \text { : } \tag{27}
\end{equation*}
$$

$T$ his $m$ eans that $m=m^{0}$ and $m$ ultipolar $m$ om ents $w$ ith di erent azim uthalcharge distribution are not able to couple or interact am ong them. $T$ his yields to
which is a sym $m$ etric $m$ atrix.

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